

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of:

ARAVIND PADMANABHAN, ET AL.

Docket: H0002237

Serial Number: 10/068,273

Group Art Unit: 1771

Filed: February 7, 2002

Examiner: Hai Vo

For: LIGHT EMITTING PHOTONIC CRYSTALS

<u>UPDATED INFORMATION DISCLOSURE STATEMENT</u>

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

SEP 0 5 2003

The undersigned wishes to update this file by citing the references enumerated on the enclosed PTO 1449.

The Commissioner is authorized to charge the \$180.00 fee for consideration of this Information Disclosure Statement to deposit account 01-1125. The Commissioner is authorized to charge any additional fees which may be necessitated by this paper, to deposit account 01-1125.

Respectfully submitted.

Righard S. Robert Reg. No. 27,941 P.O. Box 484

Princeton, New Jersey 08542 Date: September 2, 2003

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail, postage pre-paid in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on September 2, 2003

Richard S. Roberts Reg.No. 27941 n S 2005 ORM PTO-1449 ATTY. DOCKET NO: SERIAL NO U.S. DEPARTMENT OF H0002237 10/068,273 COMMERCE 32) PATENT AND TRADEMARK OFFICE APPLICANT: INFORMATION DISCLOSURE ARAVIND PADMANABHAN, ET AL. STATEMENT BY APPLICANT FILING DATE: GROUP: February 7, 2002 1771 (Use several sheets if necessary) **U.S. PATENT DOCUMENTS** FILING DATE **EXAMIN** DOCUMENT NUMBER DATE CLASS SUBCLASS NAME INITIAL APPROPRIATE AA AB AC AD AE FOREIGN PATENT DOCUMENTS TRANSLATION DOCUMENT NUMBER DATE COUNTRY CLASS **SUBCLASS** AF AG OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.) Bertone, J., et al., Phys. Rev. Lett. 83, 300-303 (1999); "Thickness Dependence of the Optical Properties AH of Ordered Silica-Air and Air-Polymer Photonic Crystals". Blanco, A., et al., Nature 405, 437-440 (2000); "Large-Scale Synthesis of a Silicon Photonic Crystal ΑĪ With a Complete Three-Dimensional Bandgap Near 1.5 Micrometres". Canham, L.T., Appl. Phys. Lett. 57 (1990), 1046-1048; "Silicon Quantum Wire Array Fabrication by ΑJ Electro-Chemical and Chemical Dissolution of Wafers". Chomski, E., et al., Chem. Vap. Dep. 2, 8-13 (1996); "New Forms of Luminescent Silicon: Silicon-Silica AK Composite Mesostructures". Dag O., et al., Adv. Mater. 11, 474-480 (1999); "Photoluminescent Silicon Clusters in Oriented Hexagonal AL Mesoporous Silica Film". John, Phys. Rev. Lett. 58, 2486-2489 (1987); "Strong Localization of Photons in Certain Disordered AM Dielectric Superlattices". Lin, S.Y., et al., IEEE J. Lightware Technol. 17, 1944-1947 (1999); "A Three-Dimensional Optical AN Photonic Crystal". Noda, S., et al., IEEE J. Lightware Technol. 17, 1948-1955 (1999); "Alignment and Stacking of Semi-AO Conductor Photonic Bandgaps by Wafer-Fusion". Uhlir, Jr., A., Bell System Tech. J., 35, (1956), 333-347; "Electrolytic Shaping of Germanium and AP Silicon". Yablonovitch, Phys. Rev. Lett. 58, 2059-2062 (1987) "Inhibited Spontaneous Emission in Solid-State AQ Physics and Electronics".

Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

DATE CONSIDERED

EXAMINER